

DESCRIPTION

The ICPLW2601 and ICPLW2611 devices each consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output.

These devices belong to Isocom wide body package range optocouplers.

FEATURES

- High Speed 10Mbit/s
- Wide Body Package
- Guaranteed Performance from -40°C to 85°C
- Strobable Logic Gate Output
- Minimum Common Mode Transient Immunity 10kV/µs at V_{CM} 1000V (ICPLW2611)
- High AC Isolation Voltage 5000V_{RMS}
- Pb Free and RoHS Compliant
- Safety Approvals Pending

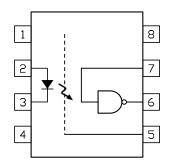
APPLICATIONS

- Line Receivers, Data Communication
- LSTTL to TTL, LSTTL or 5V CMOS
- Data Multiplexing
- Pulse Transformer Replacement
- Switch Mode Power Supplies
- Ground Loop Elimination
- Computer Peripheral Interface

ORDER INFORMATION

- Add SM after PN for Surface Mount
- Add SMT&R after PN for Surface Mount Tape & Reel





- l NC
- 2 Anode
- 3 Cathode
- 4 NC
- 5 GND
- 6 V₀
- $V_{\rm E}$
- V_{CC}

85mW

A 0.1µF bypass Capacitor must be connected between Pins 8 and 5.

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Input

Forward Current	50mA
Reverse Voltage	5V
Power dissipation	100mW

Output

Output Current	50mA
Output Voltage	7.0V
Supply Voltage	7.0V
Enable Input Voltage	5.5V
(maximum 500mV above V _{CC})	

Power Dissipation

Total Package

(10s)

Isolation Voltage	$5000V_{\text{RMS}}$
Operating Temperature	−40 to 85°C
Junction Temperature	125°C
Storage Temperature	−55 to 125°C
Lead Soldering Temperature	260°C

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Truth Table (Positive Logic)

Input	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н
Н	NC	L
L	NC	Н



ELECTRICAL CHARACTERISTICS ($T_A = -40$ to 85°C unless otherwise specified)

INPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	V_{F}	$I_F = 10 \text{mA}$		1.4	1.8	V
Forward Voltage Temperature Coefficient	$\Delta V_F/\Delta T$	$I_F = 10 \text{mA}$	nA -1.9			mV/°C
Reverse Voltage	V_R	$I_R = 100 \mu A, T_A = 25 ^{\circ} C$	5.0			V
Input Capacitance	C_{IN}	$V_F = 0V, f = 1MHz$		70		pF

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Low Level Supply Current	I_{CCH}	$I_F = 0$ mA, $V_{CC} = 5.5$ V $V_E = 0.5$ V		6.5	10	mA
Low Level Supply Current	I_{CCL}	$I_F = 10 \text{mA}, V_{CC} = 5.5 \text{V}$ $V_E = 0.5 \text{V}$		8	13	mA
High Level Enable Current	I_{EH}	$V_{CC} = 5.5V, V_E = 2.0V$		-0.6	-1.6	mA
Low Level Enable Current	I_{EL}	$V_{CC} = 5.5V, V_E = 0.5V$		-0.8	-1.6	mA
High Level Enable Voltage	V_{EH}	$I_F = 10 \text{mA}, \ V_{CC} = 5.5 \text{V}$	2.0			V
Low Level Enable Voltage	$ m V_{EL}$	$I_F = 10 \text{mA}, V_{CC} = 5.5 \text{V}$			0.8	V

COUPLED

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
High Level Output Current	I_{OH}	$I_F = 250 \mu A, \ V_E = 2.0 V \\ V_{CC} = V_O = 5.5 V$		2.1	100	μΑ
Low Level Output Voltage	V_{OL}	$I_F = 5mA, V_E = 2.0V$ $V_{CC} = 5.5V, I_{OL} = 13mA$		0.35	0.6	V
Input Threshold Current	I_{FT}	$V_{CC} = 5.5V, V_E = 2.0V$ $V_O = 0.6V, I_{OL} = 13mA$		3.0	5	mA



ELECTRICAL CHARACTERISTICS (T_A = -40 to 85°C, V_{CC} = 5V, I_F = 7.5mA unless otherwise specified)

SWITCHING

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Propagation Delay Time to High Output Level	$t_{ m PHL}$	$R_L = 350\Omega$ $C_L = 15pF$		35	100	ns
Propagation Delay Time to Low Output Level	$t_{\rm PLH}$	$T_A = 25^{\circ}C$		40	100	
Pulse Width Distortion	$ t_{PHL}$ - $t_{PLH} $	$R_L = 350\Omega$ $C_L = 15pF$		5	40	
Output Rise Time (10% to 90%)	$t_{\rm r}$			40		
Output Fall Time (90% to 10%)	${ m t_f}$			10		
Enable Propagation Delay Time to High Output Level	t _{ELH}	$\begin{aligned} V_{EH} &= 3.0V \\ R_L &= 350\Omega \\ C_L &= 15 pF \end{aligned}$		15		
Enable Propagation Delay Time to Low Output Level	t _{EHL}			15		



ELECTRICAL CHARACTERISTICS (T_A = -40 to 85°C, V_{CC} = 5V, I_F = 7.5mA unless otherwise specified)

SWITCHING

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Common Mode Transient Immunity at Logic High		$\begin{split} ICPLW2601 \\ I_F = 0mA, V_{OH} = 2.0V \\ R_L = 350\Omega \\ V_{CM} = 50Vp\text{-}p \\ T_A = 25^{\circ}C \end{split}$	5			kV/μs
		$ICPLW2611$ $I_F = 0mA, V_{OH} = 2.0V$ $R_L = 350\Omega$ $V_{CM} = 400Vp-p$ $T_A = 25^{\circ}C$	10			
		$\begin{split} & ICPLW2611 \\ & I_F = 0 mA, V_{OH} = 2.0 V \\ & V_E = V_{CC} \\ & R_L = 350 \Omega \\ & V_{CM} = 400 Vp-p \\ & T_A = 25^{\circ} C \end{split}$	20			
Common Mode Transient Immunity at Logic Low	CM_L	$\begin{split} ICPLW2601 \\ I_F = 7.5 mA, V_{OL} = 0.8 V \\ R_L = 350 \Omega \\ V_{CM} = 50 V p - p \\ T_A = 25 ^{\circ} C \end{split}$	5			kV/μs
		$ICPLW2611 \\ I_F = 7.5 mA, \ V_{OL} = 0.8 V \\ R_L = 350 \Omega \\ V_{CM} = 400 V p - p \\ T_A = 25 ^{\circ} C$	10			
		$\begin{split} ICPLW2611 \\ I_F = 7.5 mA, \ V_{OL} = 0.8 V \\ V_E = V_{CC} \\ R_L = 350 \Omega \\ V_{CM} = 400 Vp-p \\ T_A = 25^{\circ} C \end{split}$	20			

ISOLATION

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Isolation Voltage	$V_{\rm ISO}$	RH = $40-60\%$, t = 1 min T _A = 25 °C	5000			V_{RMS}

Device is considered a two terminal device: pins 1 to 4 are shorted together and pins 5 to 8 are shorted together.



ELECTRICAL CHARACTERISTICS

Notes:

- V_{CC} supply must be bypassed by a 0.1μF capacitor or larger with good frequency characteristics and should be connected as close as possible to the package V_{CC} and GND pins.
- Enable Input: No pull up resistor regired as the device has an internal pull up resistor.
- t_{PLH}: measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the
 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- t_{PHL}: measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the
 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- t_r: measured from the 10% to 90% level on the LOW to HIGH transition of the output voltage pulse.
- $t_{\rm f}$: measured from the 90% to 10% level on the HIGH to LOW transition of the output voltage pulse.
- t_{ELH}: measured from the 1.5V level on the HIGH to LOW transition of the input Enable voltage pulse to the
 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- t_{EHL}: measured from the 1.5V level on the LOW to HIGH transition of the input Enable voltage pulse to the
 1.5V level on the HIGH to LOW transition of the output voltage pulse.
- CM_H : the maximum tolerable rate of rise of the Common Mode voltage to ensure the output will remain in the HIGH state (i.e., $V_O > 2.0V$).
- CM_L : the maximum tolerable rate of rise of the Common Mode voltage to ensure the output will remain in the LOW state (i.e., $V_O < 0.8V$).



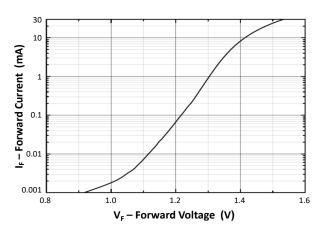


Fig 1 Forward Current vs Forward Voltage

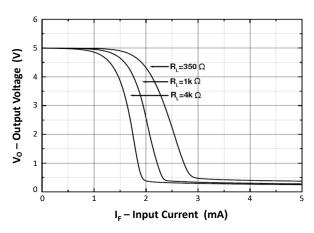


Fig 3 Output Voltage vs Input Current

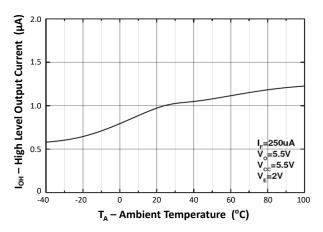


Fig 5 High Level Output Current vs Ambient Temperature

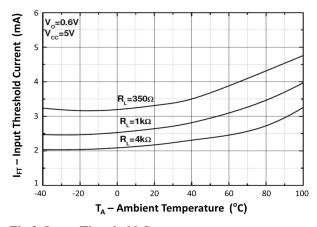


Fig 2 Input Threshold Current vs Ambient Temperature

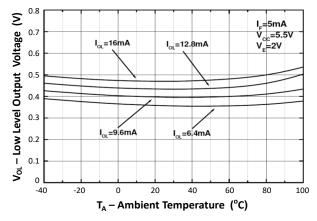


Fig 4 Low Level Output Voltage vs Ambient Temperature

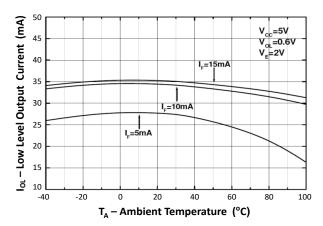


Fig 6 Low Level Output Current vs Ambient Temperature



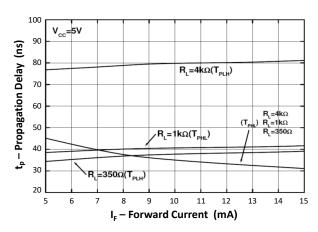


Fig 7 Propagation Delay vs Forward Current

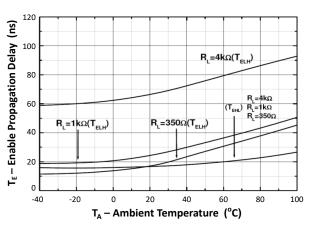


Fig 9 Enable Propagation Delay vs Ambient Temperature

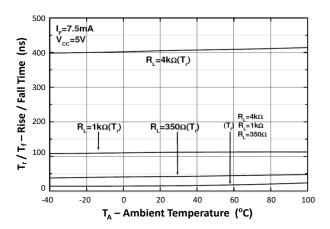


Fig 11 Rise Time / Fall Time vs Ambient Temperature

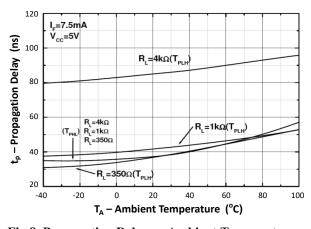


Fig 8 Propagation Delay vs Ambient Temperature

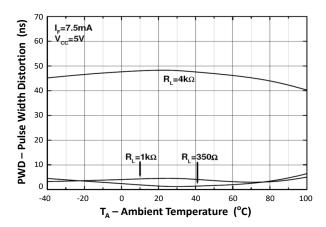
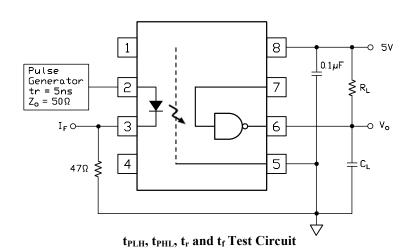
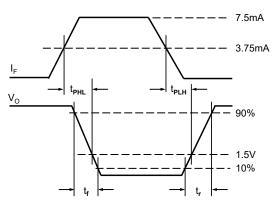
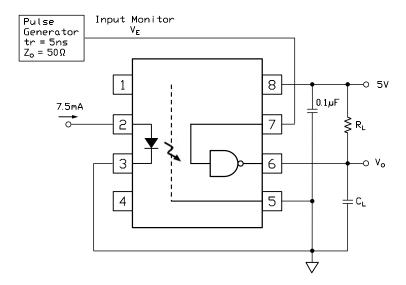


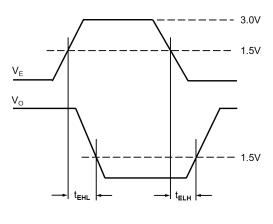
Fig 10 Pulse Width Distortion vs Ambient Temperature





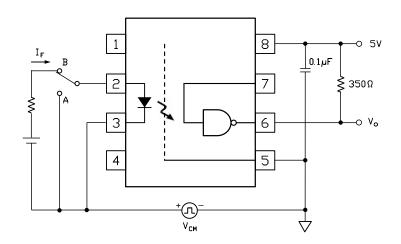


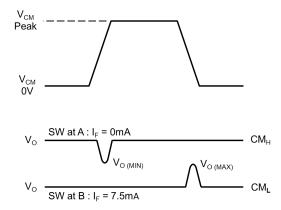




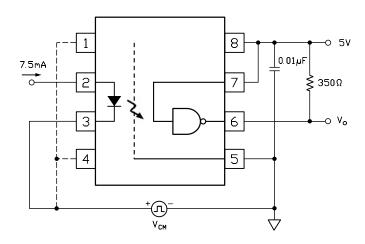
 t_{ELH} and $t_{EHL} \, Test \, Circuit$







Common Mode Transient Immunity Test Circuit



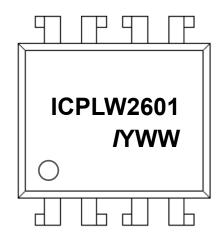
ICPLW2611: Recommended Drive Circuit for High Common Mode Transient Immunity



ORDER INFORMATION

	ICPLW2601, ICPLW2611							
After PN	After PN PN Description Pack							
None	ICPLW2601, ICPLW2611	Wide Body DIP8	40 pcs per tube					
SM	ICPLW2601SM, ICPLW2611SM	Surface Mount	40 pcs per tube					
SMT&R	ICPLW2601SMT&R ICPLW2611SMT&R	Surface Mount Tape & Reel	500 pcs per reel					

DEVICE MARKING Example : ICPLW2601



ICPLW2601 denotes Device Part Number

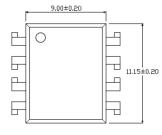
I denotes IsocomY denotes Year code

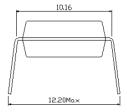
WW denotes 2 digit Week Code

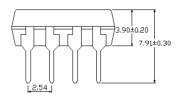


PACKAGE DIMENSIONS (mm)

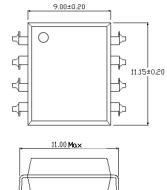
DIP

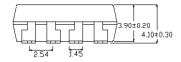






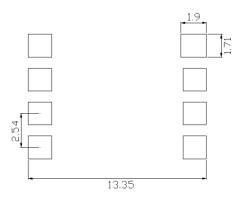
SMD





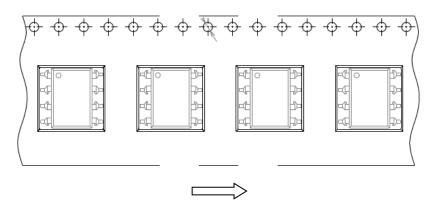
RECOMMENDED PAD LAYOUT FOR SMD (mm)

12.30±0.30

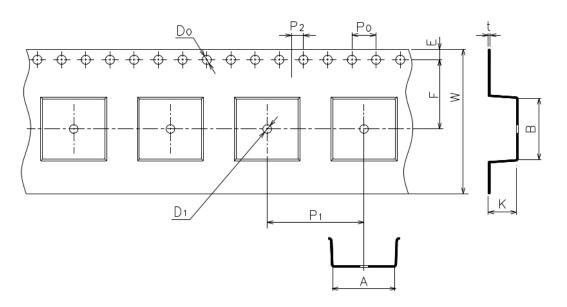




TAPE AND REEL PACKAGING



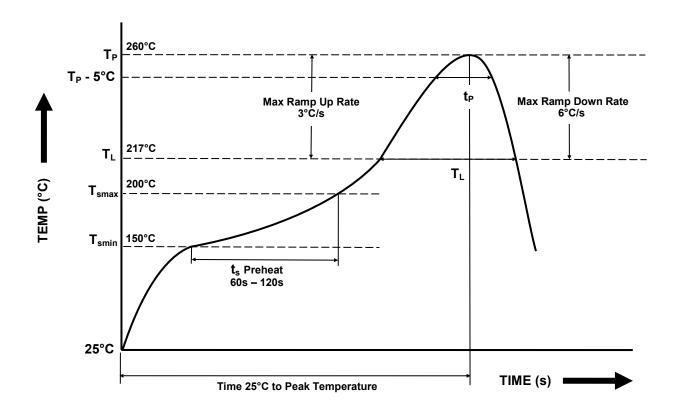
Direction of feed from reel



Dimension	Α	В	D ₀	D ₁	E	F
mm	12.7±0.1	11.45±0.1	1.5±0.1	1.5±0.1	1.75±0.1	11.5±0.1
Dimension	P ₀	P ₁	P ₂	t	W	к
mm	4.0±0.1	16.0±0.1	2.0±0.1	0.4±0.05	24.00±0.3	4.6±0.1



IR REFLOW SOLDERING TEMPERATURE PROFILE One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
$ \begin{array}{l} \textbf{Preheat} \\ \textbf{- Min Temperature } (T_{SMIN}) \\ \textbf{- Max Temperature } (T_{SMAX}) \\ \textbf{- Time } T_{SMIN} \ \text{to } T_{SMAX} \left(t_s \right) \end{array} $	150°C 200°C 60s - 120s
$\begin{tabular}{ll} \textbf{Soldering Zone} \\ - & \begin{tabular}{ll} \textbf{Peak Temperature } (T_P) \\ - & \begin{tabular}{ll} \textbf{Time at Peak Temperature } (T_L) \\ - & \begin{tabular}{ll} \textbf{Liquidous Temperature } (T_P - 5^{\circ}C) \\ - & \begin{tabular}{ll} \textbf{Time minimized above } T_L (t_L) \\ - & \begin{tabular}{ll} \textbf{Ramp Up Rate } (T_L \ to \ T_P) \\ - & \begin{tabular}{ll} \textbf{Ramp Down Rate } (T_P \ to \ T_L) \\ \end{tabular} \end{tabular}$	260°C 10s max 217°C 30s max 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate (T _{smax} to T _P)	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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